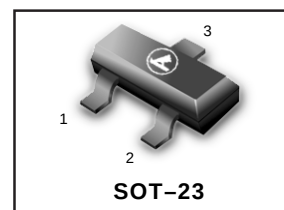


Silicon Hot-Carrier Diodes

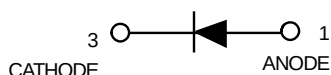
Schottky Barrier Diodes

LMBD301LT1G



These devices are designed primarily for high-efficiency UHF and VHF detector applications. They are readily adaptable to many other fast switching RF and digital applications. They are supplied in an inexpensive plastic package for low-cost, high-volume consumer and industrial/commercial requirements. They are also available in a Surface Mount package.

- EXtremely Low Minority Carrier Lifetime -15ps(Typ)
- Very Low Capacitance -1.5pF(Max)@V_R=15V
- Low Reverse Leakage -I_R=13 nAdc(Typ) LMBD301
- We declare that the material of product compliance with RoHS requirements.



MAXIMUM RATINGS(T_J=125°C unless otherwise noted)

Rating	symbol	value	unit
Reverse Voltage	V _R	30	Volts
Forward Power Dissipation	P _F		
@TA=25 °C		280	200 mW
Derate above 25 °C		2.8	2.0 mW/°C
Operating Junction	T _J		°C
Temperature Range		-55 to +125	
Storage Temperature Range	T _{sto}	-55 to +150	°C

DEVICE MARKING

LMBD301LT1G= 4T

ELECTRICAL CHARACTERISTICS(T_A=25 °C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage(I _R =10μA)	V _{(BR)R}	30	—	—	Volts
Total Capacitance(V _R =15V,f=1.0MHz,)Figure1	C _T	—	0.9	1.5	pF
Reverse Leakage(V _R =25V)Figure3	I _R	—	13	200	nAdc
Forward Voltage(IF=1.0mAdc)Figure4	V _F	—	0.38	0.45	Vdc
Forward Voltage(IF=10mAdc)Figure4	V _F	—	0.52	0.6	Vdc

NOTE:LMBD301LT1G is also available in bulk packaging.Use **LMBD301LT1G** as the device title to order this device in bulk.

Ordering Information

Device	Marking	Shipping
LMBD301LT1G	4T	3000/Tape&Reel
LMBD301LT3G	4T	10000/Tape&Reel

LMBD301LT1G

TYPICAL ELECTRICAL CHARACTERISTICS

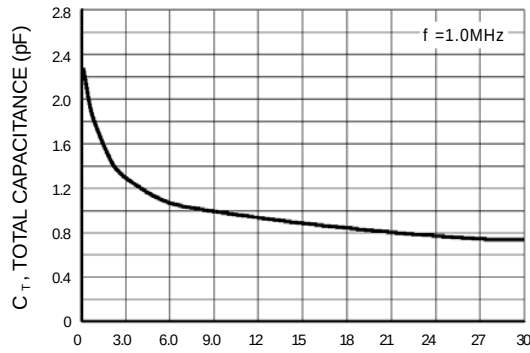


Figure 1. Total Capacitance

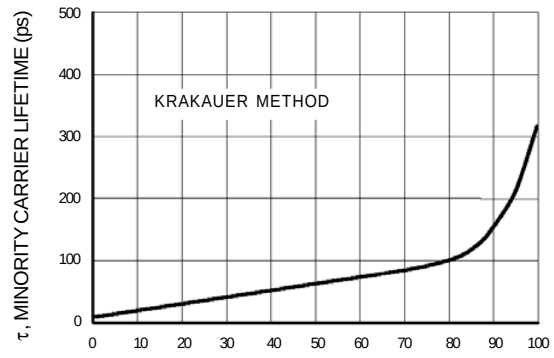


Figure 2. Minority Carrier Lifetime

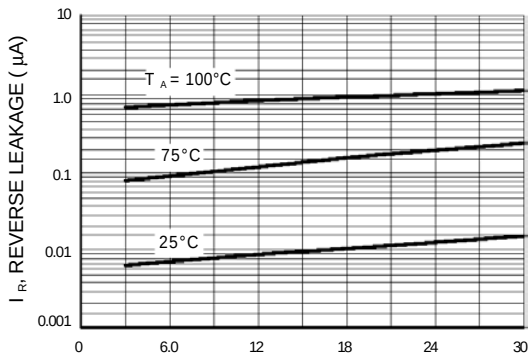


Figure 3. Reverse Leakage

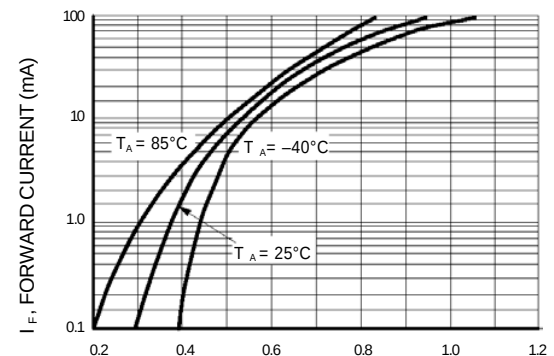


Figure 4. Forward Voltage

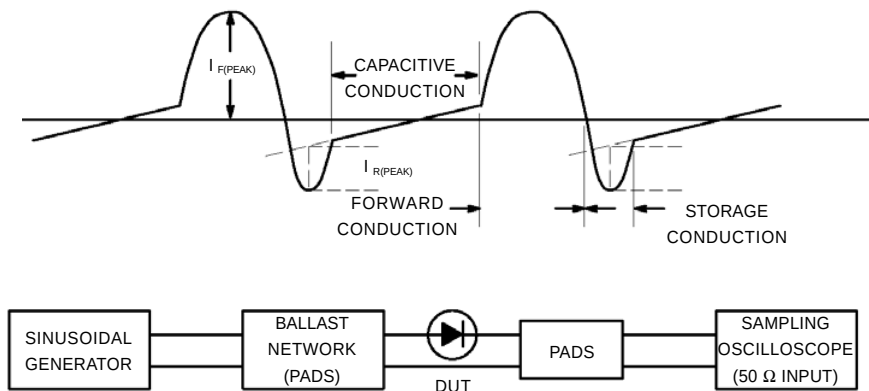
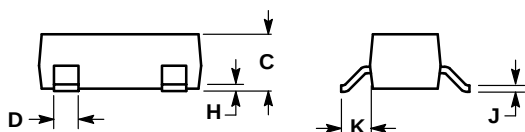
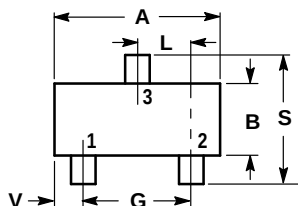


Figure 5. Krakauer Method of Measuring Lifetime

LMBD301LT1G

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. ANODE
 2. NO CONNECTION
 3. CATHODE

